NSN 5961-01-083-0926

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-083-0926 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 0.150 inches **Overall Height:** 0.040 inches **Overall Width:** 0.125 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 45.0 collector to base voltage, dc all transistor and 45.0 collector to emitter voltage, dc all transistor and 5.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector preset all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No